General purpose transistor (isolated transistor and diode)

EML4/UML4N

2SC5585 and RB521S-30 are housed independently in a EMT5 or UMT5 package.

Applications

DC / DC converter Motor driver

● Features

1) Tr : Low VcE(sat) Di : Low VF

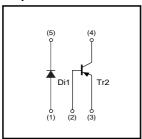
2) Small package

Structure

PNP Silicon epitaxial planar transistor Schottky barrier diode

The following characteristics apply to both Di1 and Tr2.

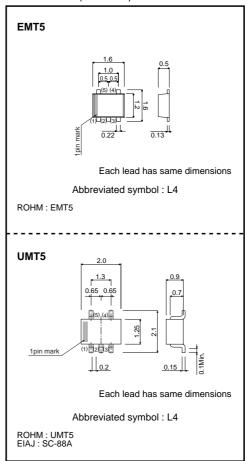
●Equivalent circuit



Packaging specifications

Туре	EML4	UML4N
Package	EMT5	UMT5
Marking	L4	L4
Code	T2R	TR
Basic ordering unit(pieces)	8000	3000

●Dimensions (Unit: mm)





● Absolute maximum ratings (Ta=25°C)

Di1

Parameter	Symbol	Limits	Unit
Average rectified forward current	lo	200	mA
Forward current surge peak (60Hz, 1∞)	IFSM	1	Α
Reverse voltage (DC)	VR	30	V
Junction temperature	Tj	125	°C

Tr2

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-15	V
Collector-emitter voltage	Vceo	-12	V
Emitter-base voltage	Vево	-6	V
Collector current	Ic	-500	mA
Collector current	ICP	-1	Α
Power dissipation	Pd	120	mW *
Junction temperature	Tj	150	°C

^{*} Each terminal mounted on a recommended.

Di1/DTr2

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	150	mW *
Storage temperature	Tstg	-55 to +125	°C

^{*} Each terminal mounted on a recommended.

●Electrical characteristics (Ta=25°C)

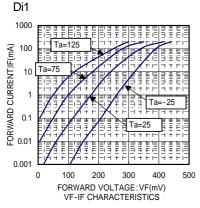
Di1

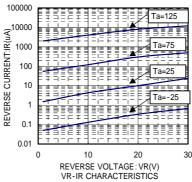
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	0.40	0.50	V	I=200mA
Reverse current	IR	_	4.0	30	μΑ	V _R =10V

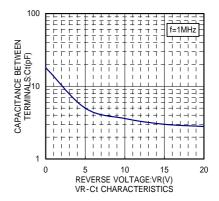
Tr2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-12	-	-	V	Ic=-1mA
Collector-base breakdown voltage	ВУсво	-15	-	-	V	Ic=-10μA
Emitter-base breakdown voltage	ВУЕВО	-6	-	-	V	I _E =-10μA
Collector cut-off current	Ісво	-	-	-100	nA	Vcb=-15V
Emitter cut-off current	ІЕВО	-	-	-100	nA	V _{EB} =-6V
Collector-emitter saturation voltage	VCE(sat)	-	-100	-250	mV	Ic=-200mA, Iв=-10mA
DC current gain	hfe	270	-	680	_	Vce=-2V, Ic=-10mA
Transition frequency	f⊤	-	260	-	MHz	Vce=-2V, Ie=10mA, f=100MHz
Collector output capacitance	Cob	-	6.5	-	pF	Vcb=-10V, Ie=0mA, f=1MHz

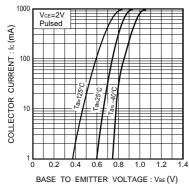
•Electrical characteristic curves

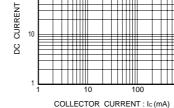






Tr2





1000

100

GAIN: he

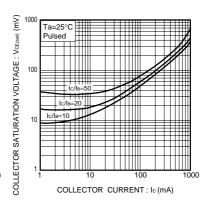
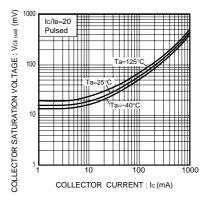
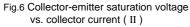


Fig.3 Grounded emitter propagation characteristics

Fig.4 DC current gain vs. collector current

Fig.5 Collector-emitter saturation voltage vs. collector current (I)





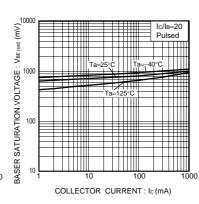


Fig.7 Base-emitter saturation voltage vs. collector current

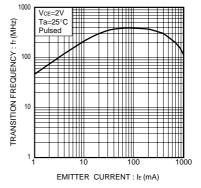


Fig.8 Gain bandwidth product vs. emitter current

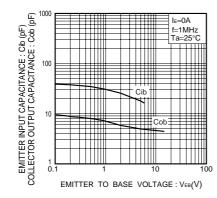


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

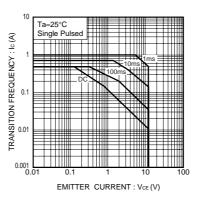


Fig.10 Safe operation area

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